

TPH4R606NH,L1Q

TPH4R606NH,L1Q Information

www.heisen		TPH4R606NH,L1Q Toshiba Semiconductor and Storage Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single MOSFET N CH 60V 32A 8-SOP ADV 8-PowerVDFN For the pricing/inventory/lead time, please contact	
For Referen	ce Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

E-mail: salesdept@heisener.com

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



TPH4R606NH,L1Q Specifications

Manufacturer Part Number	TPH4R606NH,L1Q
Manufacturer	Toshiba Semiconductor and Storage
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	8-PowerVDFN
Series	U-MOSVIII-H
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	60V
Current - Continuous Drain (Id) @ 25°C	32A (Ta)
Drive Voltage (Max Rds On, Min Rds On)	6.5V, 10V
Vgs(th) (Max) @ Id	4V @ 500µA
Gate Charge (Qg) (Max) @ Vgs	49nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	3965pF @ 30V
Vgs (Max)	$\pm 20 \mathrm{V}$
FET Feature	-
Power Dissipation (Max)	1.6W (Ta), 63W (Tc)
Rds On (Max) @ Id, Vgs	4.6 mOhm @ 16A, 10V
Operating Temperature	150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	8-SOP Advance (5x5)
Package / Case	8-PowerVDFN
	Report errors?

TPH4R606NH,L1Q Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

TPH4R606NH,L1Q Payment Methods





If you have any question about TPH4R606NH,L1Q, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com